TOSHIBA Schottky Barrier Rectifier Stack Trench Schottky Barrier Type

# 3 0 Q W K 2 C Z 4 7

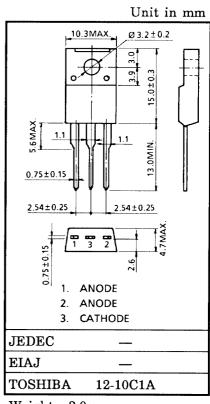
Switching Type Power Supply Application Converter & Chopper Application

• Repetitive peak reverse voltage: V<sub>RRM</sub> = 120 V

- Peak Forward Voltage: V<sub>FM</sub> = 0.85 V (max)
- Average output recified current: IO = 30 A
- Low switching losses and output noise.

### **Maximum Ratings**

Characteristics	Symbol	Rating	Unit	
Repetitive peak reverse voltage	V <sub>RRM</sub>	120	V	
Average output recified current	Ι <sub>Ο</sub>	30	А	
Peak one cycle surge forward current (non-repetitive, sine wave)	I <sub>FSM</sub>	250 (50 Hz)	А	
Junction temperature	Tj	-40~150	°C	
Storage temperature range	T <sub>stg</sub>	-40~150	°C	
Screw Torque	_	0.6	N∙m	



#### Weight : 2.0g

## **Electrical Characteristics (Ta = 25°C)**

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Peak forward voltage	V <sub>FM</sub>	I <sub>FM</sub> = 15 A	_	_	0.85	V
Repetitive peak reverse current	I <sub>RRM</sub>	V <sub>RRM</sub> = Rated (120 V)	_	_	50	μΑ
Junction capacitance	Cj	V <sub>R</sub> = 10 V, f = 1.0 MHz	_	227	_	pF
Thermal resistance	R <sub>th (j-c)</sub>	DC Total, Junction to case	_	_	2.5	°C/W

Note: V<sub>FM</sub>, I<sub>RRM</sub>, C<sub>j</sub>: A value of one cell.

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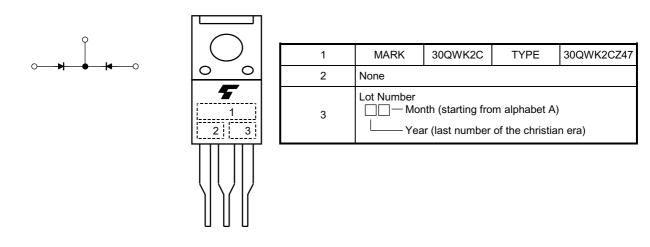
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#### Polarity

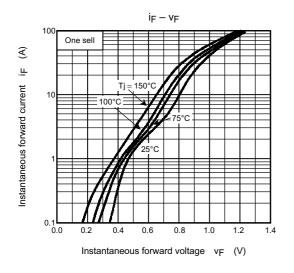
Marking

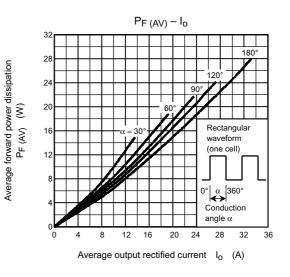


## **Handling Precaution**

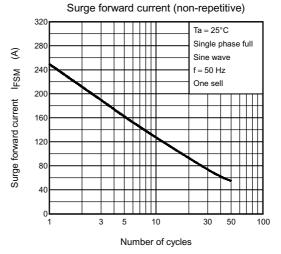
Schottky barrier diodes are having large-reverse-current-leakage characteristic compare to other rectifier products. This current leakage and not proper operating temperature or voltage may cause thermal run. Please take forward and reverse loss into consideration when you design.

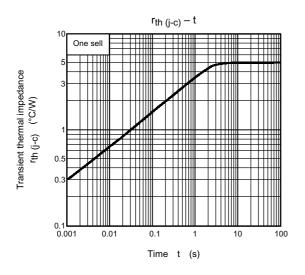
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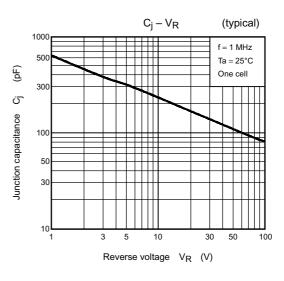




Tc max – I<sub>o</sub> Average forward power dissipation Tc max (°C) Rectangular waveform (one cell) 0° ά Conduction angle  $\alpha$ Average output rectified current Io (A)







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